## MC14551B

## Quad 2-Channel Analog Multiplexer/Demultiplexer

The MC14551B is a digitally-controlled analog switch. This device implements a 4PDT solid state switch with low ON impedance and very low OFF Leakage current. Control of analog signals up to the complete supply voltage range can be achieved.

## Features

- Triple Diode Protection on All Control Inputs
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Analog Voltage Range $\left(\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{EE}}\right)=3.0$ to 18 V

Note: $\mathrm{V}_{\mathrm{EE}}$ must be $\leq \mathrm{V}_{\mathrm{SS}}$

- Linearized Transfer Characteristics
- Low Noise - $12 \mathrm{nV} \sqrt{\text { Cycle }}, \mathrm{f} \geq 1.0 \mathrm{kHz}$ typical
- For Low R ${ }_{\text {ON }}$, Use The HC4051, HC4052, or HC4053 High-Speed CMOS Devices
- Switch Function is Break Before Make
- NLV Prefix for Automotive and Other Applications Requiring

Unique Site and Control Change Requirements; AEC-Q100
Qualified and PPAP Capable

- This Device is $\mathrm{Pb}-$ Free and is RoHS Compliant


## MAXIMUM RATINGS

| Parameter | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| DC Supply Voltage Range <br> (Referenced to $\left.\mathrm{V}_{\mathrm{EE}}, \mathrm{V}_{\mathrm{SS}} \geq \mathrm{V}_{\mathrm{EE}}\right)$ | $\mathrm{V}_{\mathrm{DD}}$ | -0.5 to +18.0 | V |
| Input or Output Voltage (DC or Transient) <br> (Referenced to $\mathrm{V}_{\mathrm{SS}}$ for Control Input and <br> $\mathrm{V}_{\mathrm{EE}}$ for Switch I/O) | $\mathrm{V}_{\text {in }}, \mathrm{V}_{\text {out }}$ | -0.5 to $\mathrm{V}_{\mathrm{DD}}$ <br> +0.5 | V |
| Input Current (DC or Transient), <br> per Control Pin | $\mathrm{I}_{\text {in }}$ | $\pm 10$ | mA |
| Switch Through Current | $\mathrm{I}_{\mathrm{sw}}$ | $\pm 25$ | mA |
| Power Dissipation, per Package (Note 1) | $\mathrm{P}_{\mathrm{D}}$ | 500 | mW |
| Ambient Temperature Range | $\mathrm{T}_{\mathrm{A}}$ | -55 to +125 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $\mathrm{T}_{\text {stg }}$ | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |
| Lead Temperature (8-Second Soldering) | $\mathrm{T}_{\mathrm{L}}$ | 260 | ${ }^{\circ} \mathrm{C}$ |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Temperature Derating: "D/DW" Package: $-7.0 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ From $65^{\circ} \mathrm{C}$ To $125^{\circ} \mathrm{C}$

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, $\mathrm{V}_{\text {in }}$ and $\mathrm{V}_{\text {out }}$ should be constrained to the range $\mathrm{V}_{S S} \leq\left(\mathrm{V}_{\text {in }}\right.$ or $\left.\mathrm{V}_{\text {out }}\right) \leq \mathrm{V}_{\mathrm{DD}}$ for control inputs and $\mathrm{V}_{\mathrm{EE}} \leq\left(\mathrm{V}_{\text {in }}\right.$ or $\left.\mathrm{V}_{\text {out }}\right)$ $\leq V_{\text {DD }}$ for Switch I/O.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either $\mathrm{V}_{\mathrm{SS}}, \mathrm{V}_{\mathrm{EE}}$ or $\mathrm{V}_{\mathrm{DD}}$ ). Unused outputs must be left open.

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## ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.


| $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=\operatorname{Pin} 16 \\ & \mathrm{~V}_{\mathrm{SS}}=\operatorname{Pin} 8 \\ & \mathrm{~V}_{\mathrm{EE}}=\operatorname{Pin} 7 \end{aligned}$ | Control | ON |
| :---: | :---: | :---: |
|  | 0 | W0 X0 Y0 Z0 |
|  | 1 | W1 X1 Y1 Z1 |

NOTE: Control Input referenced to $\mathrm{V}_{\mathrm{SS}}$, Analog Inputs and Outputs reference to $\mathrm{V}_{\mathrm{EE}}$. $\mathrm{V}_{\mathrm{EE}}$ must be $\leq \mathrm{V}_{\mathrm{SS}}$.

## ORDERING INFORMATION

| Device | Package | Shipping $^{\dagger}$ |
| :--- | :---: | :---: |
| MC14551BDG | SOIC-16 <br> (Pb-Free) | 48 Units / Rail |
| MC14551BDR2G | SOIC-16 <br> (Pb-Free) | $2500 /$ Tape \& Reel |
| NLV14551BDR2G* | SOIC-16 <br> (Pb-Free) | $2500 /$ Tape \& Reel |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

## ELECTRICAL CHARACTERISTICS

| Characteristic | $\mathrm{V}_{\mathrm{DD}}$ | Test Conditions | Symbol | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | Min | Max | Min | Typ (Note 2) | Max | Min | Max |  |

SUPPLY REQUIREMENTS (Voltages Referenced to $\mathrm{V}_{\mathrm{EE}}$ )

| Power Supply Voltage Range | - | $\mathrm{V}_{\mathrm{DD}}-3.0 \geq \mathrm{V}_{\text {SS }} \geq \mathrm{V}_{\mathrm{EE}}$ | $\mathrm{V}_{\mathrm{DD}}$ | 3.0 | 18 | 3.0 | - | 18 | 3.0 | 18 | V |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Quiescent Current Per Package | $\begin{aligned} & 5.0 \\ & 10 \\ & 15 \end{aligned}$ | Control Inputs: $\mathrm{V}_{\text {in }}=$ <br> $V_{S S}$ or $V_{D D}$, <br> Switch I/O: $\mathrm{V}_{\mathrm{EE}} \leq \mathrm{V}_{\mathrm{I} / \mathrm{O}}$ $\leq \mathrm{V}_{\mathrm{DD}}$, and $\Delta \mathrm{V}_{\text {switch }} \leq$ 500 mV (Note 3 ) | IDD | $\begin{aligned} & - \\ & \text { - } \end{aligned}$ | $\begin{aligned} & 5.0 \\ & 10 \\ & 20 \end{aligned}$ | - | $\begin{aligned} & 0.005 \\ & 0.010 \\ & 0.015 \end{aligned}$ | $\begin{aligned} & 5.0 \\ & 10 \\ & 20 \end{aligned}$ | - | $\begin{aligned} & 150 \\ & 300 \\ & 600 \end{aligned}$ | $\mu \mathrm{A}$ |
| Total Supply Current (Dynamic Plus Quiescent, Per Package) | $\begin{aligned} & 5.0 \\ & 10 \\ & 15 \end{aligned}$ | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ only (The channel component, $\left(V_{\text {in }}-V_{\text {out }}\right) / R_{\text {on }}$, is not included.) | $\mathrm{I}_{\mathrm{D}(\mathrm{AV})}$ |  $(0.07 \mu \mathrm{~A} / \mathrm{kHz}) \mathrm{f}+\mathrm{I}_{\mathrm{DD}}$ <br> Typical $(0.20 \mu \mathrm{~A} / \mathrm{kHz}) \mathrm{f}+\mathrm{I}_{\mathrm{DD}}$ <br>  $(0.36 \mu \mathrm{~A} / \mathrm{kHz}) \mathrm{f}+\mathrm{I}_{\mathrm{DD}}$ |  |  | $\begin{aligned} & (0.07 \mu \mathrm{~A} / \mathrm{kHz}) \mathfrak{f}+\mathrm{I}_{\mathrm{DD}} \\ & (0.20 \mu \mathrm{~A} / \mathrm{kHz}) \mathrm{f}+\mathrm{I}_{\mathrm{DD}} \\ & (0.36 \mu \mathrm{~A} / \mathrm{kHz}) \mathrm{f}+\mathrm{I}_{\mathrm{DD}} \end{aligned}$ |  |  |  | $\mu \mathrm{A}$ |

CONTROL INPUT (Voltages Referenced to $\mathrm{V}_{\mathrm{SS}}$ )

| Low-Level Input Voltage | 5.0 | $\mathrm{R}_{\text {on }}=$ per spec, | $\mathrm{V}_{\mathrm{IL}}$ | - | 1.5 | - | 2.25 | 1.5 | - | 1.5 | V |
| :--- | :---: | :--- | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | 10 | $\mathrm{I}_{\text {off }}=$ per spec |  | - | 3.0 | - | 4.50 | 3.0 | - | 3.0 |  |
|  | 15 |  | - | 4.0 | - | 6.75 | 4.0 | - | 4.0 |  |  |
| High-Level Input Voltage | 5.0 | $\mathrm{R}_{\text {on }}=$ per spec, | $\mathrm{V}_{\mathrm{IH}}$ | 3.5 | - | 3.5 | 2.75 | - | 3.5 | - | V |
|  | 10 | $\mathrm{I}_{\text {off }}=$ per spec |  | 7.0 | - | 7.0 | 5.50 | - | 7.0 | - |  |
|  | 15 |  | 11 | - | 11 | 8.25 | - | 11 | - |  |  |
| Input Leakage Current | 15 | $\mathrm{~V}_{\text {in }}=0$ or $\mathrm{V}_{\mathrm{DD}}$ | $\mathrm{I}_{\mathrm{in}}$ | - | $\pm 0.1$ | - | $\pm 0.00001$ | $\pm 0.1$ | - | $\pm 1.0$ | $\mu \mathrm{~A}$ |
| Input Capacitance | - |  | $\mathrm{C}_{\text {in }}$ | - | - | - | 5.0 | 7.5 | - | - | pF |

SWITCHES IN/OUT AND COMMONS OUT/IN — W, X, Y, $\mathbf{Z}$ (Voltages Referenced to $\mathrm{V}_{\mathrm{EE}}$ )

| Recommended Peak-toPeak Voltage Into or Out of the Switch | - | Channel On or Off | $\mathrm{V}_{1 / \mathrm{O}}$ | 0 | $V_{D D}$ | 0 | - | $\mathrm{V}_{\mathrm{DD}}$ | 0 | $\mathrm{V}_{\mathrm{DD}}$ | $V_{p-p}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Recommended Static or Dynamic Voltage Across the Switch (Note 3) (Figure 3) | - | Channel On | $\Delta \mathrm{V}_{\text {switch }}$ | 0 | 600 | 0 | - | 600 | 0 | 300 | mV |
| Output Offset Voltage | - | $\mathrm{V}_{\text {in }}=0 \mathrm{~V}$, No Load | $\mathrm{V}_{\mathrm{OO}}$ | - | - | - | 10 | - | - | - | $\mu \mathrm{V}$ |
| ON Resistance | $\begin{aligned} & 5.0 \\ & 10 \\ & 15 \end{aligned}$ | $\Delta V_{\text {switch }} \leq 500 \mathrm{mV}$ <br> (Note 3), <br> $V_{\text {in }}=V_{\text {IL }}$ or $V_{\text {IH }}$ <br> (Control), and $\mathrm{V}_{\text {in }}=0$ to <br> $V_{D D}$ (Switch) | $\mathrm{R}_{\text {on }}$ | - | $\begin{aligned} & 800 \\ & 400 \\ & 220 \end{aligned}$ | $\begin{aligned} & \text { - } \\ & \text { - } \end{aligned}$ | $\begin{gathered} 250 \\ 120 \\ 80 \end{gathered}$ | $\begin{gathered} 1050 \\ 500 \\ 280 \end{gathered}$ | $\begin{aligned} & \text { - } \\ & \text { - } \end{aligned}$ | $\begin{gathered} 1200 \\ 520 \\ 300 \end{gathered}$ | $\Omega$ |
| $\triangle$ ON Resistance Between Any Two Channels in the Same Package | $\begin{aligned} & \hline 5.0 \\ & 10 \\ & 15 \end{aligned}$ |  | $\Delta \mathrm{R}_{\text {on }}$ | - | $\begin{aligned} & 70 \\ & 50 \\ & 45 \end{aligned}$ | - | $\begin{aligned} & 25 \\ & 10 \\ & 10 \end{aligned}$ | $\begin{aligned} & 70 \\ & 50 \\ & 45 \end{aligned}$ | - | $\begin{aligned} & 135 \\ & 95 \\ & 65 \end{aligned}$ | $\Omega$ |
| Off-Channel Leakage Current (Figure 8) | 15 | $V_{\text {in }}=V_{\text {IL }} \text { or } V_{\text {IH }}$ <br> (Control) Channel to Channel or Any One Channel | $\mathrm{l}_{\text {off }}$ | - | $\pm 100$ | - | $\pm 0.05$ | $\pm 100$ | - | $\pm 1000$ | nA |
| Capacitance, Switch I/O | - | Switch Off | $\mathrm{C}_{1 / 0}$ | - | - | - | 10 | - | - | - | pF |
| Capacitance, Common O/I | - |  | $\mathrm{Co}_{0 / 1}$ | - | - | - | 17 | - | - | - | pF |
| Capacitance, Feedthrough (Channel Off) | - | Pins Not Adjacent Pins Adjacent | $\mathrm{C}_{1 / 0}$ | - | - | - | $\begin{aligned} & \hline 0.15 \\ & 0.47 \end{aligned}$ | - | - | - | pF |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
2. Data labeled "Typ" is not to be used for design purposes, but is intended as an indication of the IC's potential performance.
3. For voltage drops across the switch $\left(\Delta V_{\text {switch }}\right)>600 \mathrm{mV}$ ( $>300 \mathrm{mV}$ at high temperature), excessive $V_{D D}$ current may be drawn; i.e. the current out of the switch may contain both $V_{D D}$ and switch input components. The reliability of the device will be unaffected unless the Maximum Ratings are exceeded. (See first page of this data sheet.)

ELECTRICAL CHARACTERISTICS $\left(\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{EE}} \leq \mathrm{V}_{\mathrm{SS}}\right)$

| Characteristic | Symbol | $\begin{gathered} V_{D D}-V_{E E} \\ V d c \end{gathered}$ | Min | $\begin{gathered} \text { Typ } \\ \text { (Note } 4 \text { ) } \end{gathered}$ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Propagation Delay Times <br> Switch Input to Switch Output ( $\mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega$ ) <br> $t_{\text {PLH }}, t_{P H L}=(0.17 \mathrm{~ns} / \mathrm{pF}) \mathrm{C}_{\mathrm{L}}+26.5 \mathrm{~ns}$ <br> $t_{\text {PLL }}, \mathrm{t}_{\text {PHL }}=(0.08 \mathrm{~ns} / \mathrm{pF}) \mathrm{C}_{\mathrm{L}}+11 \mathrm{~ns}$ <br> $t_{\text {PLH }}, \mathrm{t}_{\mathrm{PHL}}=(0.06 \mathrm{~ns} / \mathrm{pF}) \mathrm{C}_{\mathrm{L}}+9.0 \mathrm{~ns}$ | $\mathrm{t}_{\text {PLH }}, \mathrm{t}_{\text {PHL }}$ | $\begin{aligned} & 5.0 \\ & 10 \\ & 15 \end{aligned}$ | - | 35 15 12 | $\begin{aligned} & 90 \\ & 40 \\ & 30 \end{aligned}$ | ns |
| Control Input to Output ( $\mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega$ ) $\mathrm{V}_{\mathrm{EE}}=\mathrm{V}_{\mathrm{SS}}$ (Figure 4) | $\mathrm{t}_{\text {PLH }}, \mathrm{t}_{\text {PHL }}$ | $\begin{aligned} & 5.0 \\ & 10 \\ & 15 \end{aligned}$ | - | $\begin{aligned} & 350 \\ & 140 \\ & 100 \end{aligned}$ | $\begin{aligned} & 875 \\ & 350 \\ & 250 \end{aligned}$ | ns |
| Second Harmonic Distortion $R_{L}=10 \mathrm{k} \Omega, f=1 \mathrm{kHz}, \mathrm{~V}_{\text {in }}=5 \mathrm{~V}_{\mathrm{p}-\mathrm{p}}$ | - | 10 | - | 0.07 | - | \% |
| Bandwidth (Figure 5) $\begin{aligned} & R_{L}=1 \mathrm{kQ}, \mathrm{~V}_{\text {in }}=1 / 2\left(\mathrm{~V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{EE}}\right)_{\mathrm{p}-\mathrm{p}}, \\ & 20 \log \left(\mathrm{~V}_{\text {out }} / V_{\text {in }}\right)=-3 \mathrm{~dB}, C_{\mathrm{L}}=50 \mathrm{pF} \end{aligned}$ | BW | 10 | - | 17 | - | MHz |
| Off Channel Feedthrough Attenuation, Figure 5 $R_{L}=1 \mathrm{k} \Omega, V_{\text {in }}=1 / 2\left(V_{D D}-V_{E E}\right)_{p-p}, f_{\text {in }}=55 \mathrm{MHz}$ | - | 10 | - | -50 | - | dB |
| Channel Separation (Figure 6) $R_{L}=1 \mathrm{k} \Omega, V_{\text {in }}=1 / 2\left(V_{D D}-V_{E E}\right)_{p-p}, f_{\text {in }}=3 \mathrm{MHz}$ | - | 10 | - | - 50 | - | dB |
| Crosstalk, Control Input to Common O/I, Figure 7 $R 1=1 \mathrm{k} \Omega, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega$, Control $\mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$ | - | 10 | - | 75 | - | mV |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
4. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.


Figure 1. Switch Circuit Schematic


Figure 2. MC14551B Functional Diagram

## TEST CIRCUITS



Figure 3. $\Delta \mathrm{V}$ Across Switch


Figure 4. Propagation Delay Times, Control to Output

Control input used to turn ON or OFF the switch under test.


Figure 5. Bandwidth and Off-Channel Feedthrough Attenuation


Figure 7. Crosstalk, Control Input to Common O/I


Figure 6. Channel Separation (Adjacent Channels Used for Setup)


Figure 8. Off Channel Leakage


Figure 9. Channel Resistance ( $\mathrm{R}_{\mathrm{ON}}$ ) Test Circuit

TYPICAL RESISTANCE CHARACTERISTICS


Figure 10. $\mathrm{V}_{\mathrm{DD}} @ 7.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{EE}} @-7.5 \mathrm{~V}$


Figure 12. $\mathrm{V}_{\mathrm{DD}} @ 2.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{EE}} @-2.5 \mathrm{~V}$


Figure 11. $\mathrm{V}_{\mathrm{DD}} @ 5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{EE}} @-5.0 \mathrm{~V}$


Figure 13. Comparison at $25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{DD}} @-\mathrm{V}_{\mathrm{EE}}$

## APPLICATIONS INFORMATION

Figure A illustrates use of the on-chip level converter detailed in Figure 2. The 0-to-5.0 V Digital Control signal is used to directly control a $9 \mathrm{~V}_{\mathrm{p}-\mathrm{p}}$ analog signal.

The digital control logic levels are determined by $\mathrm{V}_{\mathrm{DD}}$ and $\mathrm{V}_{\mathrm{SS}}$. The $\mathrm{V}_{\mathrm{DD}}$ voltage is the logic high voltage; the $\mathrm{V}_{\mathrm{SS}}$ voltage is logic low. For the example, $\mathrm{V}_{\mathrm{DD}}=+5.0 \mathrm{~V}=$ logic high at the control inputs; $\mathrm{V}_{\mathrm{SS}}=\mathrm{GND}=0 \mathrm{~V}=$ logic low.

The maximum analog signal level is determined by $\mathrm{V}_{\mathrm{DD}}$ and $\mathrm{V}_{\mathrm{EE}}$. The $\mathrm{V}_{\mathrm{DD}}$ voltage determines the maximum recommended peak above $\mathrm{V}_{\mathrm{SS}}$. The $\mathrm{V}_{\mathrm{EE}}$ voltage determines the maximum swing below $\mathrm{V}_{\mathrm{SS}}$. For the example, $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ $=5.0 \mathrm{~V}$ maximum swing above $\mathrm{V}_{\mathrm{SS}} ; \mathrm{V}_{\mathrm{SS}}-\mathrm{V}_{\mathrm{EE}}=5.0 \mathrm{~V}$ maximum swing below $\mathrm{V}_{\mathrm{SS}}$. The example shows a $\pm 4.5 \mathrm{~V}$
signal which allows a $1 / 2 \mathrm{~V}$ margin at each peak. If voltage transients above $\mathrm{V}_{\mathrm{DD}}$ and/or below $\mathrm{V}_{\mathrm{EE}}$ are anticipated on the analog channels, external diodes ( $\mathrm{D}_{\mathrm{x}}$ ) are recommended as shown in Figure B. These diodes should be small signal types able to absorb the maximum anticipated current surges during clipping.

The absolute maximum potential difference between $\mathrm{V}_{\mathrm{DD}}$ and $\mathrm{V}_{\mathrm{EE}}$ is 18 V . Most parameters are specified up to 15 V which is the recommended maximum difference between $\mathrm{V}_{\mathrm{DD}}$ and $\mathrm{V}_{\mathrm{EE}}$.

Balanced supplies are not required. However, $\mathrm{V}_{\mathrm{SS}}$ must be greater than or equal to $\mathrm{V}_{\mathrm{EE}}$. For example, $\mathrm{V}_{\mathrm{DD}}=+10 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}$ $=+5.0 \mathrm{~V}$, and $\mathrm{V}_{\mathrm{EE}}=-3.0 \mathrm{~V}$ is acceptable. See the table below.


Figure A. Application Example


Figure B. External Schottky or Germanium Clipping Diodes

## POSSIBLE SUPPLY CONNECTIONS

| $\mathrm{V}_{\mathrm{DD}}$ <br> In Volts | $\mathbf{V}_{\mathrm{SS}}$ <br> In Volts | $\mathrm{V}_{\mathrm{EE}}$ <br> In Volts | Control Inputs <br> Logic High/Logic Low <br> In Volts | Maximum Analog Signal Range <br> In Volts |
| :---: | :---: | :---: | :---: | :---: |
| +8 | 0 | -8 | $+8 / 0$ | +8 to $-8=16 \mathrm{~V}_{\mathrm{p}-\mathrm{p}}$ |
| +5 | 0 | -12 | $+5 / 0$ | +5 to $-12=17 \mathrm{~V}_{\mathrm{p}-\mathrm{p}}$ |
| +5 | 0 | 0 | $+5 / 0$ | +5 to $0=5 \mathrm{~V}_{\mathrm{p}-\mathrm{p}}$ |
| +5 | 0 | -5 | $+5 / 0$ | +5 to $-5=10 \mathrm{~V}_{\mathrm{p}-\mathrm{p}}$ |
| +10 |  | -5 | $+10 /+5$ | +10 to $-5=15 \mathrm{~V}_{\mathrm{p}-\mathrm{p}}$ |

SOIC-16 9.90x3.90×1.50 1.27P
CASE 751B
ISSUE L
DATE 29 MAY 2024

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. DIMENSION IN MILLIMETERS. ANGLE IN DEGREES.
3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 mm PER SIDE.
5. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 mm TOTAL IN EXCESS OF THE b DIMENSION AT MAXIMUM MATERIAL CONDITION.


| MILLIMETERS |  |  |  |
| :---: | :---: | :---: | :---: |
| DIM | MIN | NOM | MAX |
| A | 1.35 | 1.55 | 1.75 |
| A1 | 0.00 | 0.05 | 0.10 |
| A2 | 1.35 | 1.50 | 1.65 |
| b | 0.35 | 0.42 | 0.49 |
| c | 0.19 | 0.22 | 0.25 |
| D | 9.90 BSC |  |  |
| E | 6.00 BSC |  |  |
| E1 | 3.90 BSC |  |  |
| e | 1.27 BSC |  |  |
| h | 0.25 | --- | 0.50 |
| L | 0.40 | 0.83 | 1.25 |
| L1 | 1.05 REF |  |  |
| O | 0 | --- | $7 \cdot$ |
| TOLERANCE OF FORM AND POSITION |  |  |  |
| aaa | 0.10 |  |  |
| bbb | 0.20 |  |  |
| ccc | 0.10 |  |  |
| ddd | 0.25 |  |  |
| eee | 0.10 |  |  |



RECOMMENDED MOUNTING FOOTPRINT
*FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE onsemi SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D

| DOCUMENT NUMBER: | 98ASB42566B |  | Document Repositon: rin red. |
| :---: | :---: | :---: | :---: |
| DESCRIPTION: | SOIC-16 9.90X3.90X1.50 1.27P |  | PAGE 1 OF 2 |

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## SOIC-16 9.90x3.90x1.50 1.27P CASE 751B ISSUE L

## GENERIC

MARKING DIAGRAM*

*This information is generic. Please refer to device data sheet for actual part marking. $\mathrm{Pb}-\mathrm{Free}$ indicator, " G " or microdot " $\mathrm{=}$ ", may or may not be present. Some products may not follow the Generic Marking.

| STYLE 1: |  | STYLE 2: |  | STYLE 3: |  | STYLE 4: |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| PIN 1. | COLLECTOR | PIN 1. | CATHODE | PIN 1. | COLLECTOR, DYE \#1 | PIN 1. | COLLECTOR, DYE \#1 |
| 2. | BASE | 2. | ANODE | 2. | BASE, \#1 | 2. | COLLECTOR, \#1 |
| 3. | Emitter | 3. | NO CONNECTION | 3. | EMITTER, \#1 | 3. | COLLECTOR, \#2 |
| 4. | NO CONNECTION | 4. | CATHODE | 4. | COLLECTOR, \#1 | 4. | COLLECTOR, \#2 |
| 5. | EMITTER | 5. | CATHODE | 5. | COLLECTOR, \#2 | 5. | COLLECTOR, \#3 |
| 6. | BASE | 6. | NO CONNECTION | 6. | BASE, \#2 | 6. | COLLECTOR, \#3 |
| 7. | COLLECTOR | 7. | ANODE | 7. | EMITTER, \#2 | 7. | COLLECTOR, \#4 |
| 8. | COLLECTOR | 8. | CATHODE | 8. | COLLECTOR, \#2 | 8. | COLLECTOR, \#4 |
| 9. | BASE | 9. | CATHODE | 9. | COLLECTOR, \#3 | 9. | BASE, \#4 |
| 10. | EMITTER | 10. | ANODE | 10. | BASE, \#3 | 10. | EMITTER, \#4 |
| 11. | NO CONNECTION | 11. | NO CONNECTION | 11. | EMITTER, \#3 | 11. | BASE, \#3 |
| 12. | EMITTER | 12. | CATHODE | 12. | COLLECTOR, \#3 | 12. | EMITTER, \#3 |
| 13. | BASE | 13. | CATHODE | 13. | COLLECTOR, \#4 | 13. | BASE, \#2 |
| 14. | COLLECTOR | 14. | NO CONNECTION | 14. | BASE, \#4 | 14. | EMITTER, \#2 |
| 15. | EMITTER | 15. | ANODE | 15. | EMITTER, \#4 | 15. | BASE, \#1 |
| 16. | COLLECTOR | 16. | CATHODE | 16. | COLLECTOR, \#4 | 16. | EMITTER, \#1 |
| STYLE 5: |  | STYLE 6: |  | STYLE 7: |  |  |  |
| PIN 1. | DRAIN, DYE \#1 | PIN 1. | CATHODE | PIN 1. | SOURCE N-CH |  |  |
| 2. | DRAIN, \#1 | 2. | CATHODE | 2. | COMMON DRAIN (OUTPUT) |  |  |
| 3. | DRAIN, \#2 | 3. | CATHODE | 3. | COMMON DRAIN (OUTPUT) |  |  |
| 4. | DRAIN, \#2 | 4. | CATHODE | 4. | GATE P-CH |  |  |
| 5. | DRAIN, \#3 | 5. | CATHODE | 5. | COMMON DRAIN (OUTPUT) |  |  |
| 6. | DRAIN, \#3 | 6. | CATHODE | 6. | COMMON DRAIN (OUTPUT) |  |  |
| 7. | DRAIN, \#4 | 7. | CATHODE | 7. | COMMON DRAIN (OUTPUT) |  |  |
| 8. | DRAIN, \#4 | 8. | CATHODE | 8. | SOURCE P-CH |  |  |
| 9. | GATE, \#4 | 9. | ANODE | 9. | SOURCE P-CH |  |  |
| 10. | SOURCE, \#4 | 10. | ANODE | 10. | COMMON DRAIN (OUTPUT) |  |  |
| 11. | GATE, \#3 | 11. | ANODE | 11. | COMMON DRAIN (OUTPUT) |  |  |
| 12. | SOURCE, \#3 | 12. | ANODE | 12. | COMMON DRAIN (OUTPUT) |  |  |
| 13. | GATE, \#2 | 13. | ANODE | 13. | GATE N-CH |  |  |
| 14. | SOURCE, \#2 | 14. | ANODE | 14. | COMMON DRAIN (OUTPUT) |  |  |
| 15. | GATE, \#1 | 15. | ANODE | 15. | COMMON DRAIN (OUTPUT) |  |  |
| 16. | SOURCE, \#1 | 16. | ANODE | 16. | SOURCE N-CH |  |  |


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